

of becoming an obstacle against increase of the operational speed and reduction of the electric power consumption.

IN THE CLAIMS

Please amend the claims to read as shown below:²

1. (Amended) A semiconductor device comprising:
 - an SOI substrate having respectively a semiconductor substrate, a dielectric layer, and a semiconductor layer;
 - a transistor having a drain region and a source region respectively formed in said semiconductor layer;
 - a gate electrode formed via a gate dielectric film on a channel region sandwiched between said drain region and said source region;
 - an interlayer dielectric film formed on said transistor;
 - a drain wiring and a source wiring formed on said interlayer dielectric film;
 - a first conductor formed in said interlayer dielectric film and connecting said drain wiring to said drain region;
 - a second conductor formed in said interlayer dielectric film and connecting said source wiring to said source region;
 - said drain region including,
 - a first part adjacent to said channel region, and

²The changes to the claims are shown using underscoring and bracketing in the attachment hereto.

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a second part formed to protrude from said first part of the drain region so that a part of outer peripheries of said second part of said drain region extends away from said gate electrode in a plan view; and

said first conductor is connected to said second part of said drain region.

5. (Amended) The semiconductor device according to claim 1, wherein said source region comprises:

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a first part adjacent to said channel region;
a second part formed to protrude from said first part of the source region so that a part of outer peripheries of said second part of said source region extends away from said gate electrode in a plan view, said second conductor connected to said second part of said source region.

REMARKS

Favorable reconsideration of this application as presently amended and in light of the following discussion is respectfully requested.

Claims 1, 2, 5, and 6 are presently active, Claims 3, 4, and 7-13 having been previously withdrawn from consideration, and Claims 1 and 5 having been amended by the present amendment.

In the Office Action, Figures 27-29 were objected to for not containing a legend such as --Prior Art --, and Figure 29 was objected to for containing reference numerals not mentioned in the description. Claims 1-2 and 5-6 were rejected under 35 U.S.C. § 103(a) as